## NSN 5961-01-185-1399

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-185-1399 **Inclosure Material:** Plastic **Overall Length:** 0.785 inches **Overall Height:** 0.300 inches **Overall Width:** 0.300 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** -600.0 collector to base voltage/static/emitter open all transistor and -40.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** -600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 650.0 milliwatts small-signal input power, common-collector preset all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: